





TH2H-6

Fully Printed Tunable Phase Shifter for L/S-Band Phased Array Application

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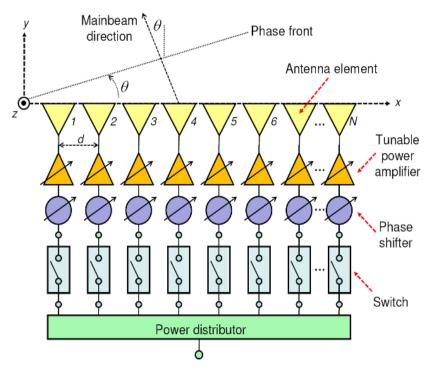


- Motivation
- Development of Low Temperature Sintered BST Thick-films
- MIM Varactor Fabrication and Measurement
- Phase Shifter Design and Simulation
- Phase Shifter Fabrication And Measurement
- Conclusion
- Outlook





- Multi frequency functionality:
 - Tunable phase shifters
 - Tunable antennas
 - Tunable filters
- A tunable component can reduce
 - Size
 - Complexity
 - power consumption



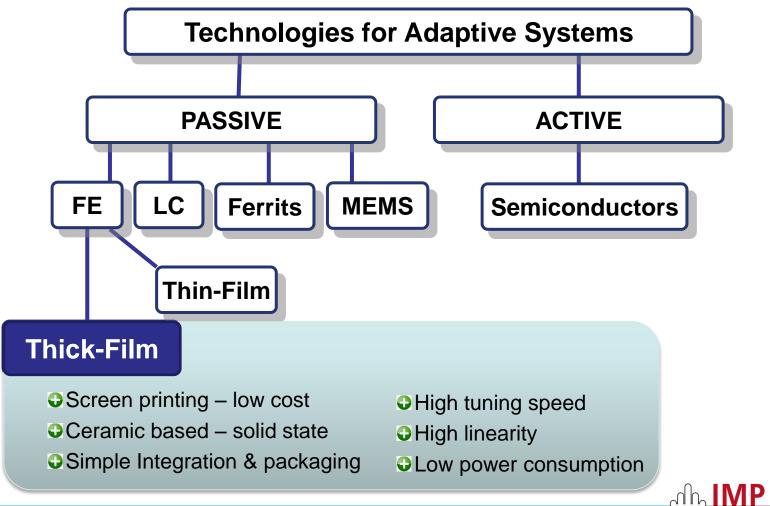
• The functional components in a tunable circuit are tunable varactors







Why BST Thick-Film?



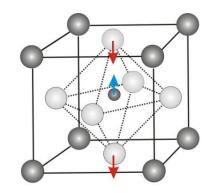




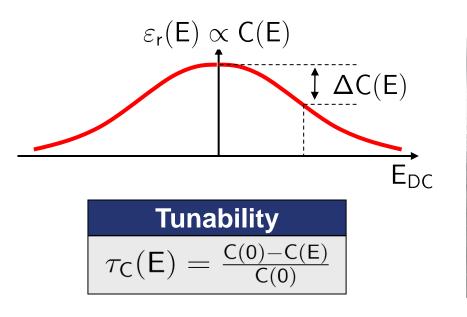
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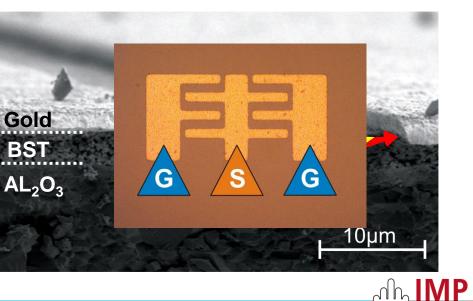
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- Tunable Dielectric : Barium-Strontium-Titanate (BST)
- > Permittivity changes by applying an electrostatic field
- Basic tunable component
 - Tunable Interdigital Capacitor (IDC)



Ba/Sr ●Ti



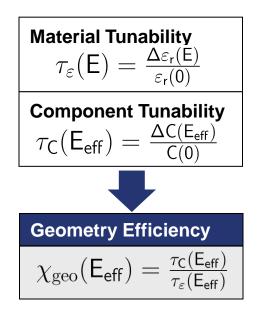


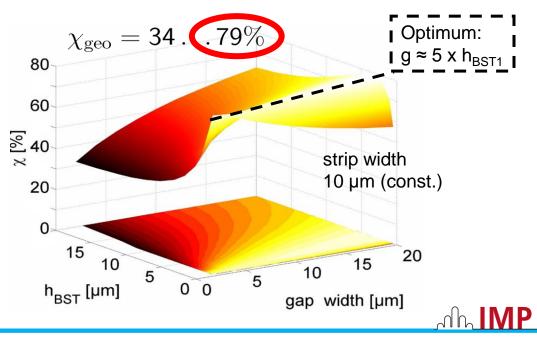






- IDC Limitations:
 - > Minimum gap is restricted \rightarrow Reduce maximum electric field per μ m
 - Delicate fabrication process
 - ➢ Low FoM
 - Geometry efficiency







MIM Varactor

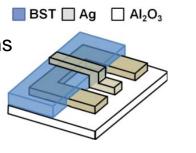


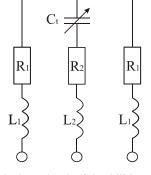


- Metal Isolator Metal Capacitors (MIM):
 - ✓ Reduce biasing voltage
 - ✓ Increase breaking voltage
 - ✓ Increase maximum tunablity
 - ✓ Improver Insertion Loss
 - ✓ Decrease number of tunable units
- MIM Varactor Layers:

metal BST

- MIM Varactor fabricated by selective printed BST and Silver film
- The bottom and top layers are metallic electrodes
- The middle layer is the BST thick-film
- Three inductances represent the electrode executions





Layout of the MIM varactor

Equivalent circuit of the MIM varactor

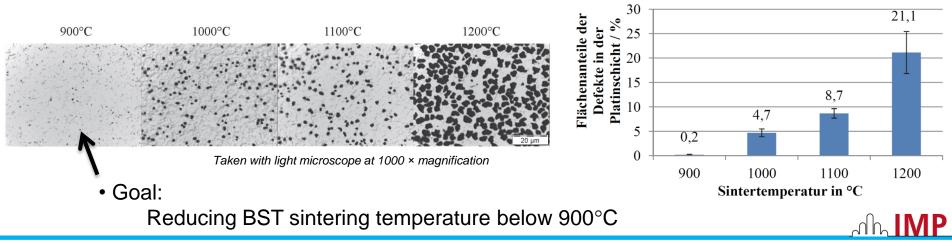


Screen Printing





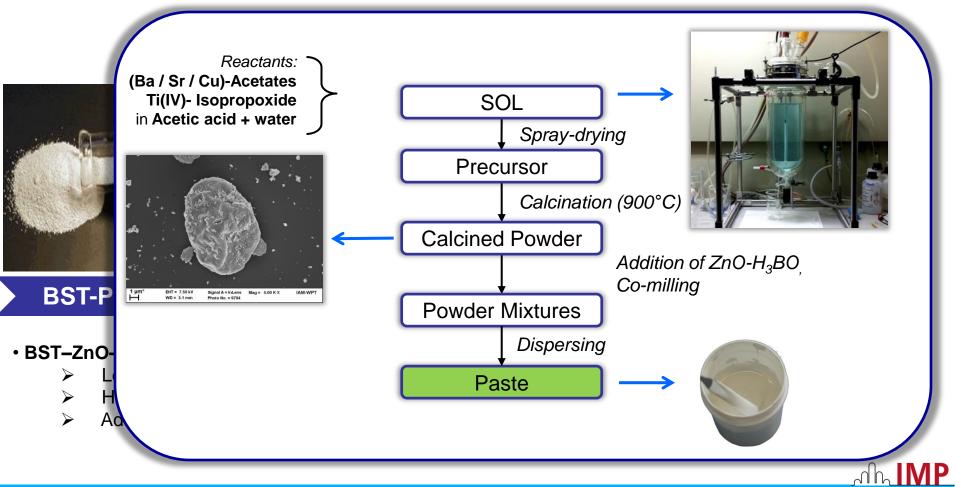
- Printing Process:
 - Fast
 - Cost effective
 - Low fabrication tolerances
- Degradation of the platinum layers
 - The increase in the number of defects in the platinum layer (200nm) on top of Al2O3 substrates (sintered 1h) at different sintering temperatures.







➤The Screen printing technology:







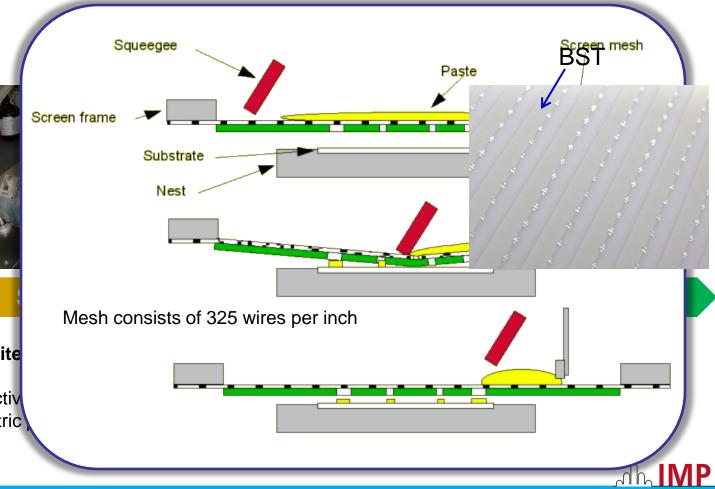


➤The Screen printing technology:



BST–ZnO–B₂O₃ composite

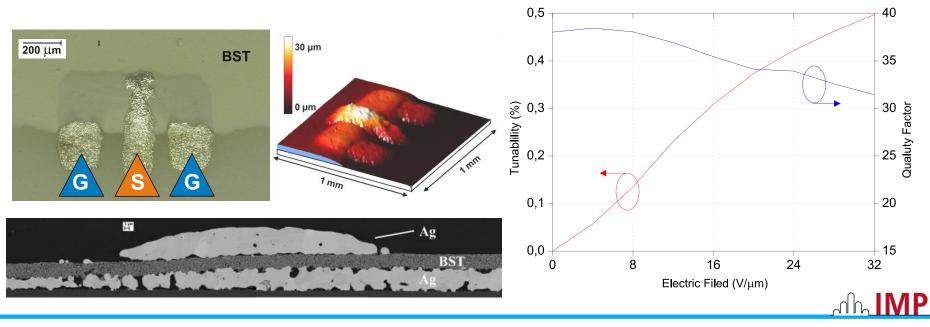
- Low porosity
- High sintering activ
- Adequate dielectric







- MIM Varactor Protoype:
 - > The fabrication is done by subsequent screen-printing and drying of each layer
 - Samples were co-fired in purified dried air at a temperature of 850°C for 1h
 - > Measurement results of the fully printed MIM varactor over the tuning voltage at 1.7 GHz
 - > By applying a maximum voltage of 160 V, a tunability of 50% is achieved
 - Relative permittivity = 210 and capacitance of 3.8 pF

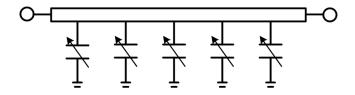




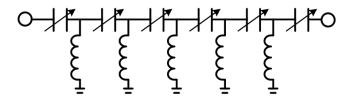


Comparison between loaded transmission line and metamaterial delay line phase shifters

Loaded transmission line phase shifter (LL)



It is a broadband transmission line with shunted varactor loadings. Its positive propagation constant is controlled by tuning varactors. Metamaterial delay line phase shifter (MM-DL)



It is a chain of cascaded band pass unit cells. It can achieve equivalently zero or negative propagation constant. Ferroelectric varactors are serial connected in the line.

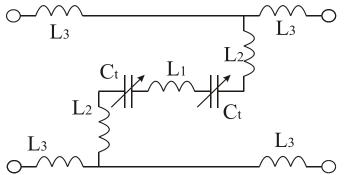
$$\beta_{RH} = -\frac{1}{\omega\sqrt{L \times C_t}} \qquad Z_{RH} = \sqrt{\frac{L}{C_t}}$$

<u>Mh IMP</u>

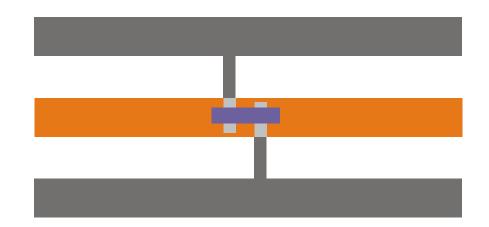




• The unit cell equivalent circuit and layout of the loaded line phase shifter









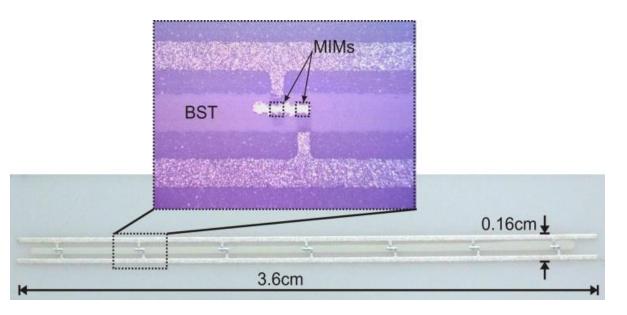


Phase Shifter Prototype



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- Tunable phase shifter prototype:
 - Center frequency at 1.7GHz
 - Simulation software ADS
 - BST line thickness 5.9µm
 - >The intersection of the top and bottom layer of each MIM varactor is 160×100µm²
 - Conductor layer thickness 13µm
 - Number of unit cells 7 unit cells



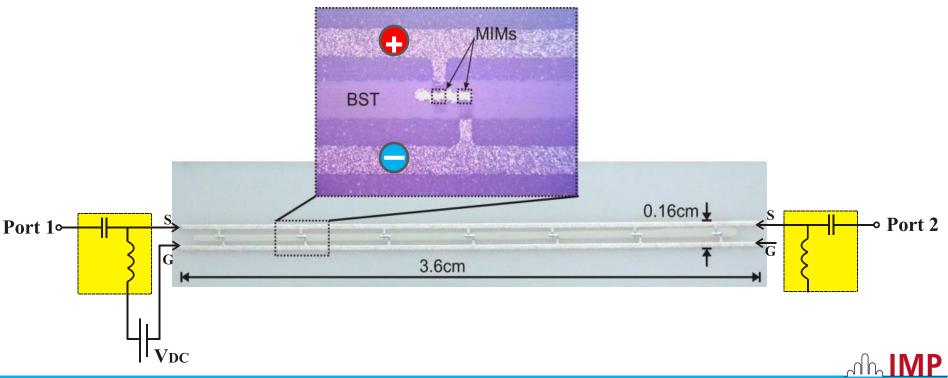


Phase Shifter Prototype



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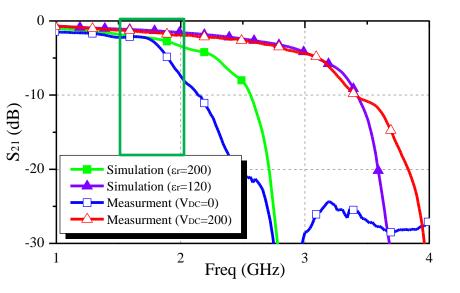
- On-Wafer measurement :
 - > Measurement in a 50 Ω system
 - Tuning voltage applied by using Bias-T
 - Tuning Voltage changed between 0 to 200 V
 - Simple biasing concept

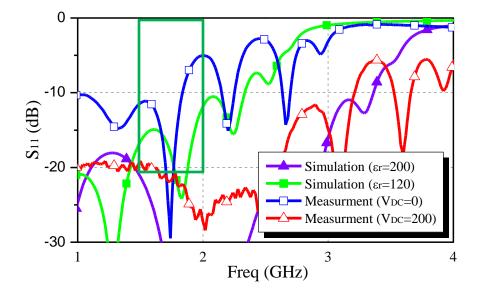






• S-Parameter Measurement Results:





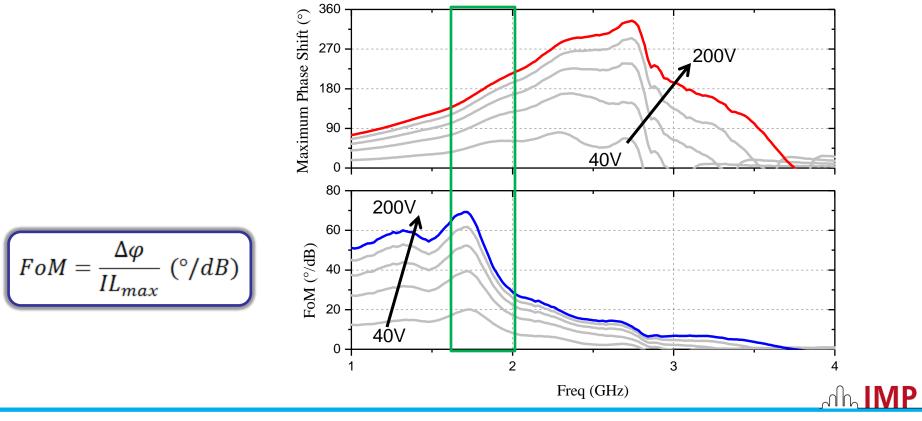
- Simulation and measurement comparison:
 - The fabrication tolerance
 - Parasitic microstrip propagation mode
 - The alignment accuracy

Mh IMP





- Phase Shift and Figure of merit (FoM):
 - > A phase shift of 158° is achieved at 1.72GHz with a FoM of 70°/dB







Conclusion

- > The Fully screen printed technology is implemented as simple, fast and low-cost process
- Fully printed MIM varactor gives a maximum tunability of 50% by applying 160V
- > A fully screen-printed load line phase shifter is fabricated and measured at L-band
- A phase shift of 158° is achieved at 1.72GHz with a FoM of 70°/dB

Freq (GHz)	Δφ (°)	FoM (°/dB)	Vmax (V)	Varactor	Sintering Temp	Ref
3	20	14.6	200	MIM*	850	[4]
2.5	4.5	6.55	250	MIM*	850	[5]
2	70	58	100	MIM/IDC	-	[6]
2.5	48	20	100	Planar	-	[13]
2.5	63	21	100	MIM *	1200	[6]
2.8	65	29	100	IDC	-	[14]
1.75	158	(70)	200	MIM*	850	This Work

*Fabricated in fully screen printed technology

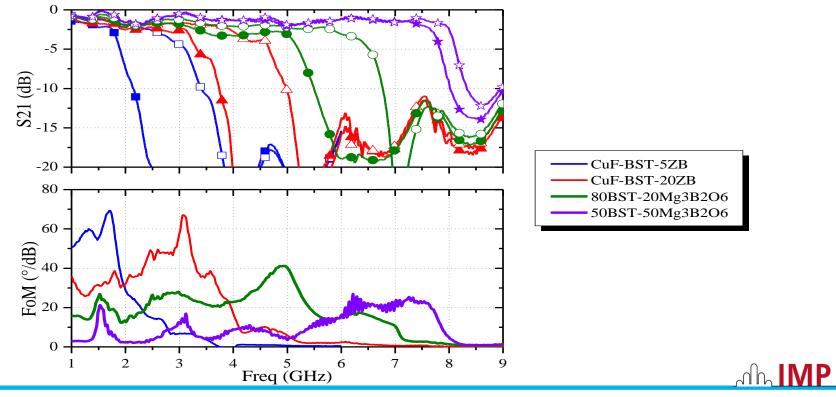
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Outlook

- > The fabricated MIM capacitor demonstrates a simple and flexible preparation
- For phased array applications, it is necessary to have 360° phase shift (16 unit cells)
- Higher operation frequencies are targeted, which can be reached by higher printing accuracy and reduced line width











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